

Shake-up replicas of excitons and trions in magneto-photoluminescence of two-dimensional hole gas

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Abstract. Recombination spectra of excitons and trions in two-dimensional hole gas are studied in two-beam magneto-PL. The singlet, dark-triplet and bright-triplet trions are all identified, and their binding energies are determined. Below the trion energies, the cyclotron replica is identified. Based on the realistic numerical calculation, this peak is attributed to the shake-up process that involves a trion bound to a neutral acceptor located inside the quantum well.

Keywords: Shake-up, photoluminescence, trion, hole gas.

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INTRODUCTION

Photoluminescence (PL) spectroscopy in magnetic fields is a powerful method to study two-dimensional (2D) electron (or hole) gas in the integral or fractional quantum Hall regime. Field evolution of the spectra carries information not only about the single-particle energy levels of 2D carriers, but also about the crucial role of exchange interaction. In this paper, we report low-temperature magneto-PL studies of a 2D hole gas. We observed recombination of neutral and positively charged excitons (trions): $X = e + h$, $X^+ = 2h + e$ [1,2], as well as of their cyclotron replicas. The analysis of optical selection rules and the numerical calculations allowed for (i) identification of all trion states and (ii) interpretation of the replica as a shake-up process [3] consisting of the recombination of a trion bound to a neutral impurity located in the quantum well, A^0X^+ , accompanied by excitation of the impurity-bound hole to a higher Landau level (LL), $A^+ \rightarrow A^0 + h^*$. This demonstrates that interactions of 2D carriers with impurities are important even in high-quality samples, with mean free path comparable to that of electrons with the highest mobility $\mu \sim 10^6 \text{ cm}^2/\text{Vs}$.

EXPERIMENT AND RESULTS

The sample was a $w = 15 \text{ nm}$ GaAs/Ga_{0.65}Al_{0.35}Al quantum well fabricated by molecular beam epitaxy on a (001) semi-insulating GaAs substrate δ C-doped in the barrier on both sides. At low temperature $T = 4.2 \text{ K}$

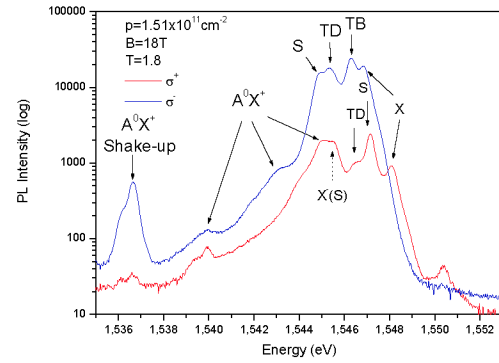


FIGURE 1. PL spectra of 15 nm GaAs/Ga_{0.65}Al_{0.35}Al quantum well in magnetic field of $B = 19\text{T}$. Note that intensity on vertical axis is shown in logarithmic scale.

the sheet concentration and mobility of the holes were $p = 1.51 \times 10^{11} \text{ cm}^{-2}$ and $\mu = 1.01 \times 10^6 \text{ cm}^2/\text{Vs}$. The measurements were carried out at temperatures down to $T = 1.8 \text{ K}$ and in magnetic fields up to $B = 23 \text{ T}$. We used Faraday configuration, with a linear polarizer and wave quarter placed together with the sample in liquid helium. To switch between σ^- and σ^+ polarizations, the direction of the magnetic field was changed. PL was excited by the $\lambda = 750 \text{ nm}$ line of Titanium Sapphire tuneable laser. The additional ion Argon line $\lambda = 514 \text{ nm}$ was used to increase the 2D electron concentration.

In Fig. 1 the PL spectra in both polarizations at $B = 18 \text{ T}$ are presented. This particular value was

